

MOSFETs Silicon N-channel MOS (U-MOSX-H)

TK5R0A15Q5

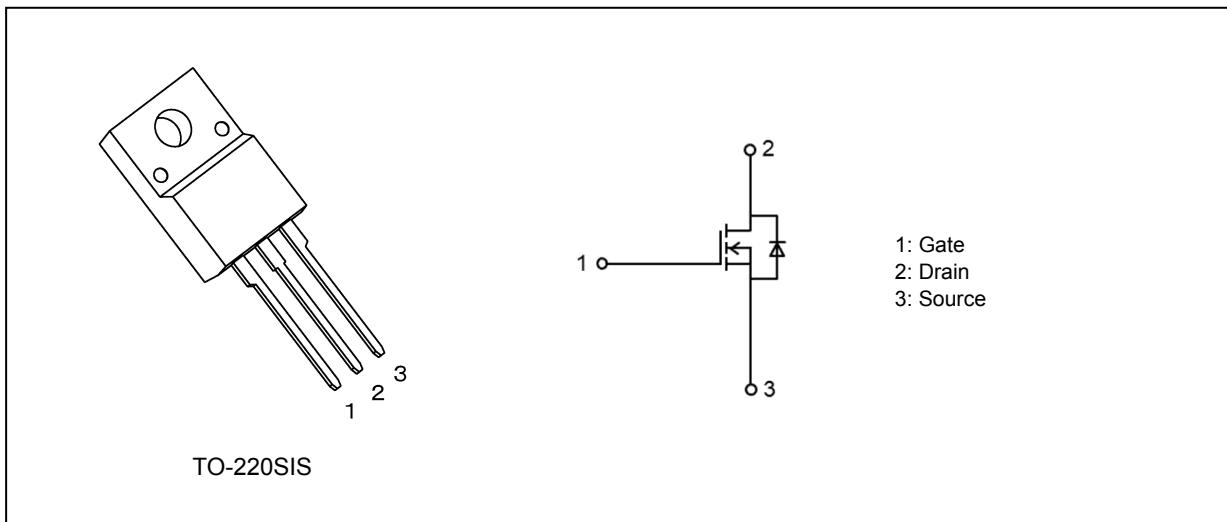
1. Applications

- High-Efficiency DC-DC Converters
- Switching Voltage Regulators
- Motor Drivers

2. Features

- (1) Fast reverse recovery time: $t_{rr} = 52$ ns (typ.)
- (2) Small reverse recovery charge : $Q_{rr} = 55$ nC (typ.)
- (3) Small gate charge: $Q_{SW} = 26$ nC (typ.)
- (4) Low drain-source on-resistance: $R_{DS(ON)} = 4.3$ mΩ (typ.) ($V_{GS} = 10$ V)
- (5) Low leakage current: $I_{DSS} = 10$ μA (max) ($V_{DS} = 150$ V)
- (6) Enhancement mode: $V_{th} = 3.1$ to 4.5 V ($V_{DS} = 10$ V, $I_D = 2.2$ mA)

3. Packaging and Internal Circuit



Start of commercial production
2024-07

4. Absolute Maximum Ratings (Note) ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V_{DSS}	150	V
Gate-source voltage	V_{GSS}	± 20	
Drain current (DC) ($T_c = 25^\circ\text{C}$) (Note 1)	I_D	76	A
Drain current (DC) (Silicon limit) (Note 1), (Note 2)	I_D	76	
Drain current (pulsed) ($t = 100\ \mu\text{s}$) (Note 1)	I_{DP}	480	
Power dissipation ($T_c = 25^\circ\text{C}$)	P_D	53	W
Single-pulse avalanche energy (Note 3)	E_{AS}	136	mJ
Single-pulse avalanche current (Note 3)	I_{AS}	76	A
Channel temperature	T_{ch}	175	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to 175	
Isolation voltage (RMS) ($t = 1.0\ \text{s}$)	$V_{ISO(\text{RMS})}$	2000	V
Mounting torque	TOR	0.6	N · m

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance ($T_c = 25^\circ\text{C}$)	$R_{th(ch-c)}$	2.78	$^\circ\text{C/W}$
Channel-to-ambient thermal resistance ($T_a = 25^\circ\text{C}$)	$R_{th(ch-a)}$	62.5	

Note 1: Ensure that the channel temperature does not exceed 175°C .

Note 2: Limited by silicon chip capability.

Note 3: $V_{DD} = 100\ \text{V}$, $T_{ch} = 25^\circ\text{C}$ (initial), $L = 23\ \mu\text{H}$, $I_{AS} = 76\ \text{A}$

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

6.1. Static Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I_{GSS}	$V_{GS} = \pm 20\text{ V}$, $V_{DS} = 0\text{ V}$	—	—	± 0.1	μA
Drain cut-off current	I_{DSS}	$V_{DS} = 150\text{ V}$, $V_{GS} = 0\text{ V}$	—	—	10	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 10\text{ mA}$, $V_{GS} = 0\text{ V}$	150	—	—	
Drain-source breakdown voltage (Note 4)	$V_{(BR)DSX}$	$I_D = 10\text{ mA}$, $V_{GS} = -20\text{ V}$	130	—	—	
Gate threshold voltage	V_{th}	$V_{DS} = 10\text{ V}$, $I_D = 2.2\text{ mA}$	3.1	—	4.5	
Drain-source on-resistance	$R_{DS(ON)}$	$V_{GS} = 8\text{ V}$, $I_D = 38\text{ A}$	—	4.5	6	
		$V_{GS} = 10\text{ V}$, $I_D = 38\text{ A}$	—	4.3	5	$\text{m}\Omega$

Note 4: If a reverse bias is applied between gate and source, this device enters $V_{(BR)DSX}$ mode. Note that the drain-source breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	C_{iss}	$V_{DS} = 75\text{ V}$, $V_{GS} = 0\text{ V}$, $f = 1\text{ MHz}$	—	7820	—	pF
Reverse transfer capacitance	C_{rss}		—	50	—	
Output capacitance	C_{oss}		—	1540	—	
Gate resistance	r_g	See Fig. 6.2.1	—	1.9	2.9	Ω
Switching time (rise time)	t_r		—	62	—	ns
Switching time (turn-on time)	t_{on}		—	95	—	
Switching time (fall time)	t_f		—	57	—	
Switching time (turn-off time)	t_{off}		—	130	—	

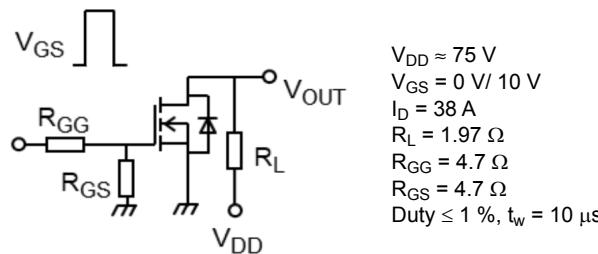


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Q_g	$V_{DD} \approx 75\text{ V}$, $V_{GS} = 10\text{ V}$, $I_D = 38\text{ A}$	—	96	—	nC
		$V_{DD} \approx 75\text{ V}$, $V_{GS} = 8\text{ V}$, $I_D = 38\text{ A}$	—	78	—	
Gate-source charge 1	Q_{gs1}	$V_{DD} \approx 75\text{ V}$, $V_{GS} = 10\text{ V}$, $I_D = 38\text{ A}$	—	44	—	
			—	11.6	—	
Gate-drain charge	Q_{gd}		—	26	—	
Gate switch charge	Q_{sw}		—	190	—	
Output charge	Q_{oss}	$V_{DS} = 75\text{ V}$, $V_{GS} = 0\text{ V}$, $f = 1\text{ MHz}$	—	—	—	

6.4. Source-Drain Characteristics ($T_a = 25^\circ\text{C}$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Reverse drain current (pulsed) (Note 5)	I_{DRP}	$t = 100 \mu\text{s}$	—	—	480	A
Diode forward voltage	V_{DSF}	$I_{DR} = 38 \text{ A}, V_{GS} = 0 \text{ V}$	—	—	-1.2	V
Reverse recovery time (Note 6)	t_{rr}	$I_{DR} = 19 \text{ A}, V_{GS} = 0 \text{ V}, -dI_{DR}/dt = 100 \text{ A}/\mu\text{s}$	—	52	78	ns
Reverse recovery charge (Note 6)	Q_{rr}		—	55	125	nC

Note 5: Ensure that the channel temperature does not exceed 175 °C.

Note 6: Defined by design.

7. Marking (Note)

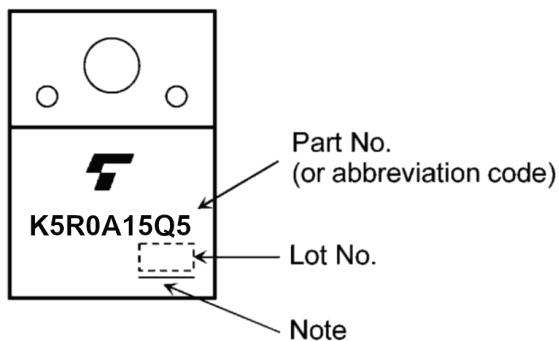


Fig. 7.1 Marking

Note: A line under a Lot No. identifies the indication of product Labels.

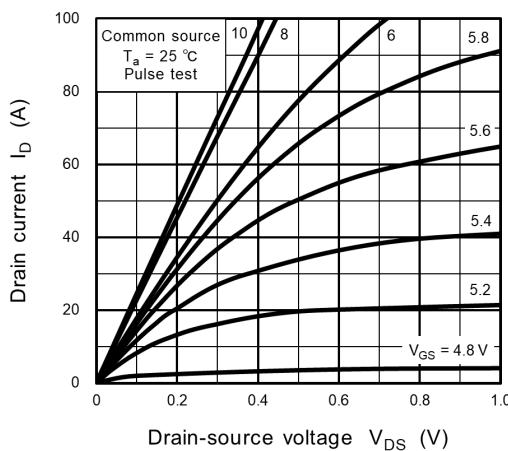
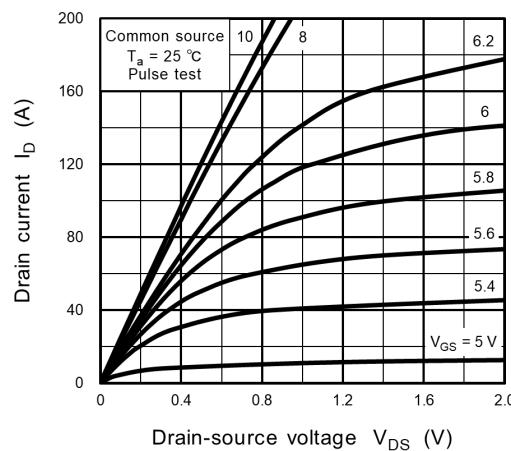
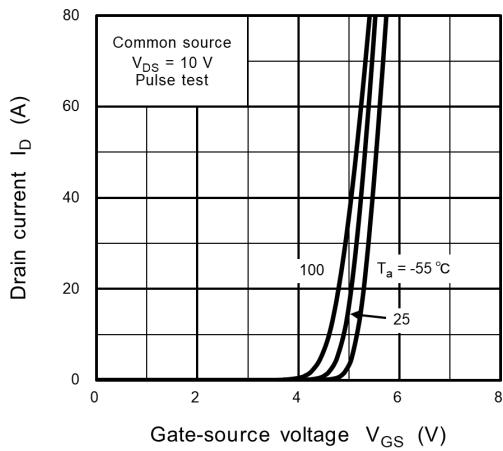
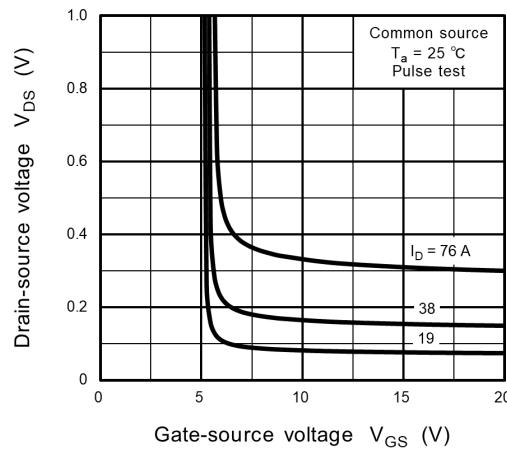
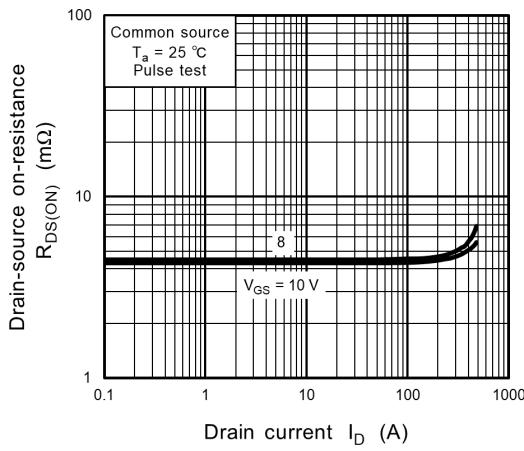
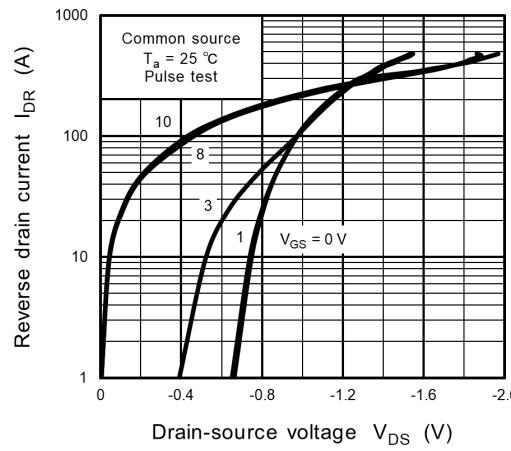
Not underlined: [[Pb]]/INCLUDES > MCV

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The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

8. Characteristics Curves (Note)

Fig. 8.1 I_D - V_{DS} Fig. 8.2 I_D - V_{DS} Fig. 8.3 I_D - V_{GS} Fig. 8.4 V_{DS} - V_{GS} Fig. 8.5 $R_{DS(ON)}$ - I_D Fig. 8.6 I_{DR} - V_{DS}

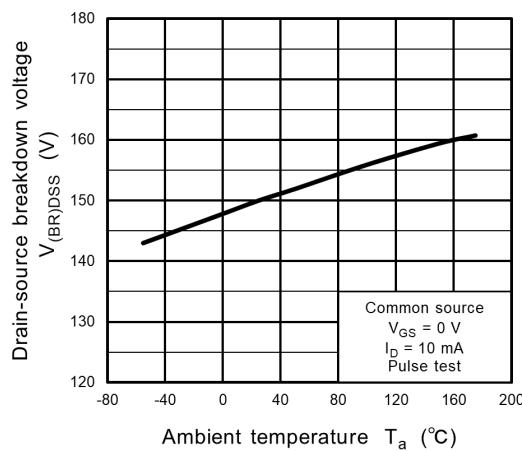


Fig. 8.7 $V_{(BR)DSS}$ - T_a

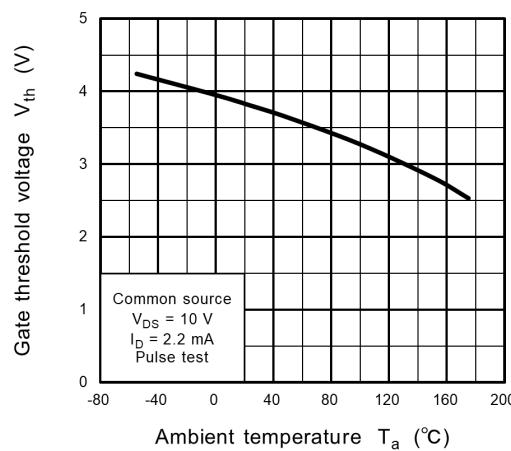


Fig. 8.8 V_{th} - T_a

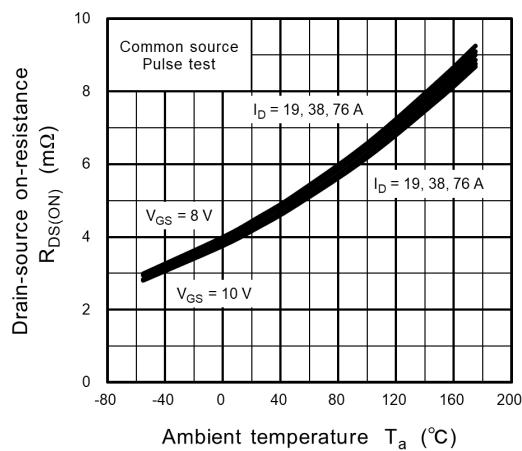


Fig. 8.9 $R_{DS(ON)}$ - T_a

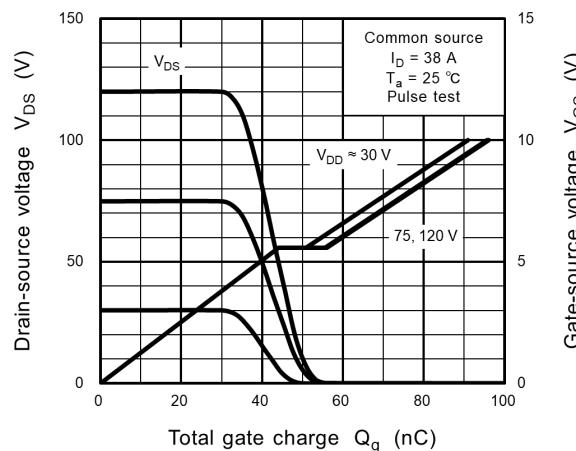


Fig. 8.10 Dynamic Input/Output Characteristics

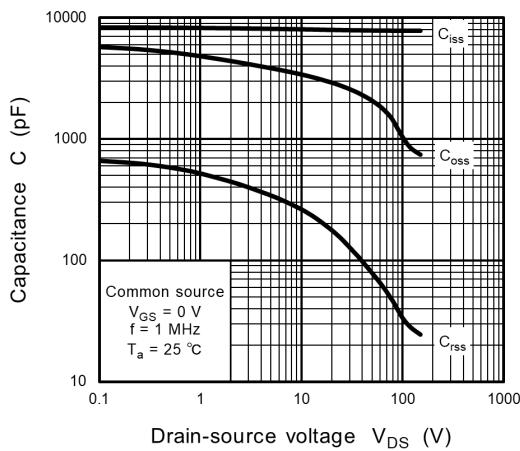


Fig. 8.11 Capacitance - V_{DS}

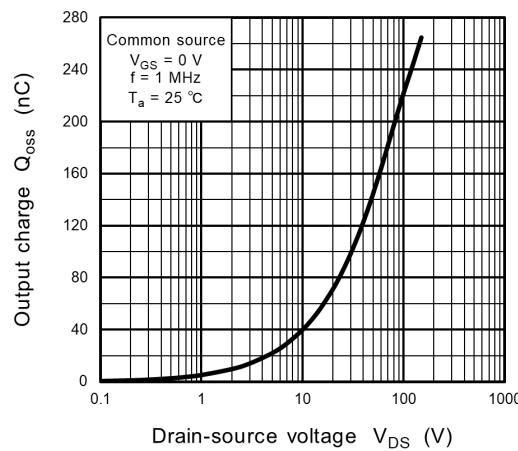
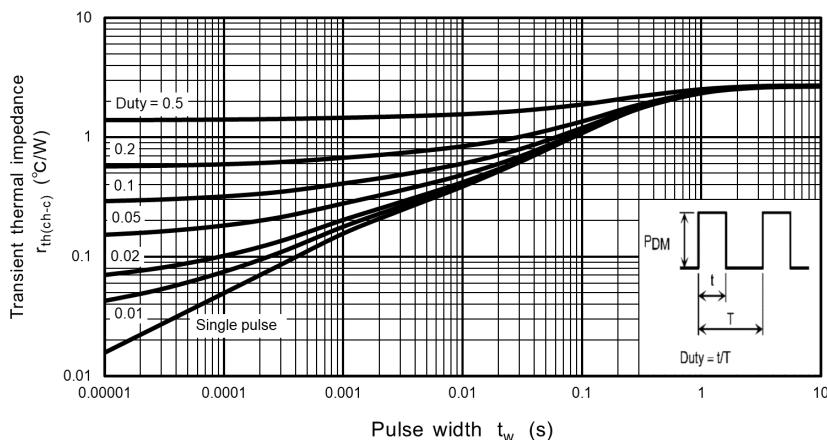
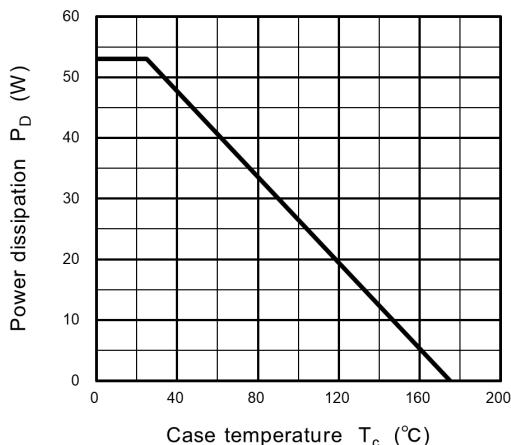


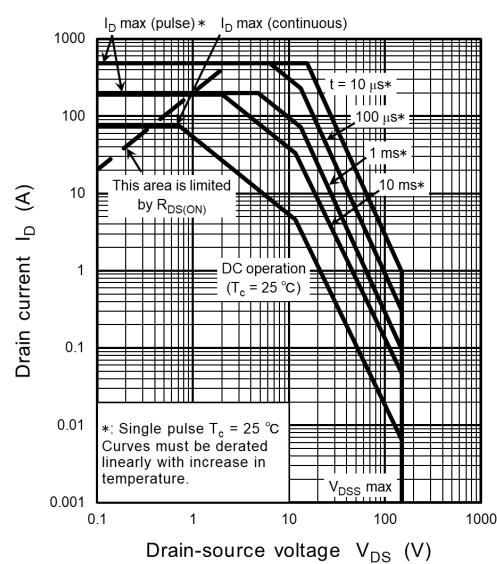
Fig. 8.12 Q_{oss} - V_{DS}



**Fig. 8.13 $r_{th} - t_w$
(Guaranteed Maximum)**



**Fig. 8.14 $P_D - T_c$
(Guaranteed Maximum)**

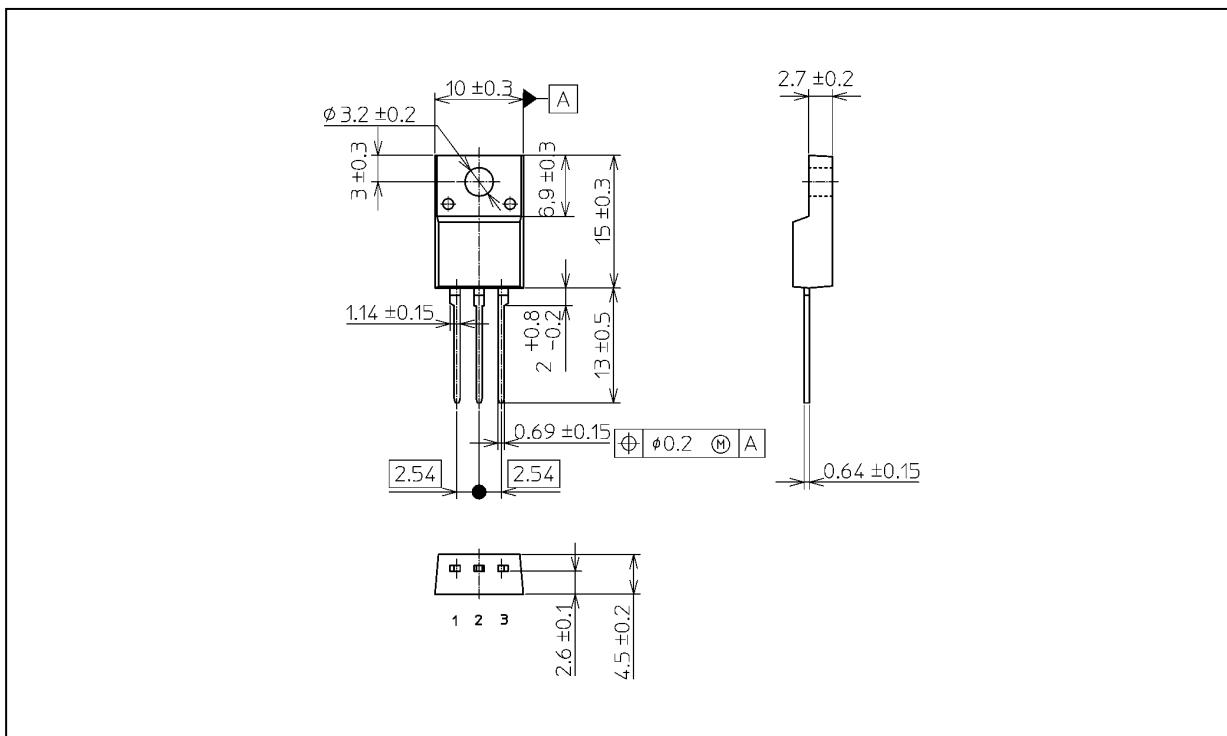


**Fig. 8.15 Safe Operating Area
(Guaranteed Maximum)**

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

Unit: mm



Weight: 1.56 g (typ.)

Package Name(s)
TOSHIBA: 2-10U1S
Nickname: TO-220SIS

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